## NSN 5962-01-352-1007

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**Body Length:** 0.540 inches **Body Width:** Between 0.245 inches and 0.300 inches **Body Height:** Between 0.045 inches and 0.100 inches **Maximum Power Dissipation Rating:** 0.6 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 5895-01-299-3419 converter, signal data **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** F-9 mil-m-38510 **Current Rating Per Characteristic:** 12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable **Terminal Surface Treatment:** Solder **Product Name:** Registered and-or gate array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds delay **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 flat leads

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N/a

**Unit Of Measure:** 

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Demilitarization:

No

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